

BCR3KM-14L

Triac

Low Power Use

REJ03G0330-0100 Rev.1.00 Aug.20.2004

Features

I_{T (RMS)}: 3 A
 V_{DRM}: 700 V

• I_{FGTI} , I_{RGTI} , I_{RGTIII} : 30 mA

Viso: 2000 V

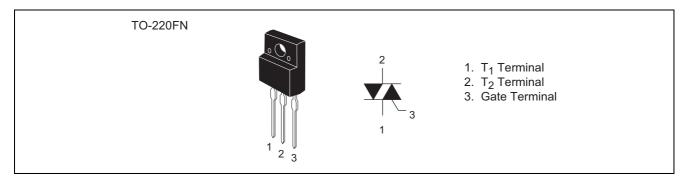
Insulated Type

• Planar Passivation Type

• UL Recognized: Yellow Card No. E223904

File No. E80271

Outline



Applications

240-V AC electric equipment, washing machine, vacuum cleaner, garbage disposer, solenoid driver, small motor control, and other general purpose control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Faranietei	Symbol	14		
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	700	V	
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V	

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Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	3.0	А	Commercial frequency, sine full wave 360° conduction, Tc = 108°C
Surge on-state current	I _{TSM}	30	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	3.7	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	3	W	
Average gate power dissipation	P _{G (AV)}	0.3	W	
Peak gate voltage	V_{GM}	6	V	
Peak gate current	I_{GM}	0.5	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	2.0	g	Typical value
Isolation voltage	Viso	2000	V	Ta = 25°C, AC 1 minute, $T_1 \cdot T_2 \cdot G$ terminal to case

Notes: 1. Gate open.

Electrical Characteristics

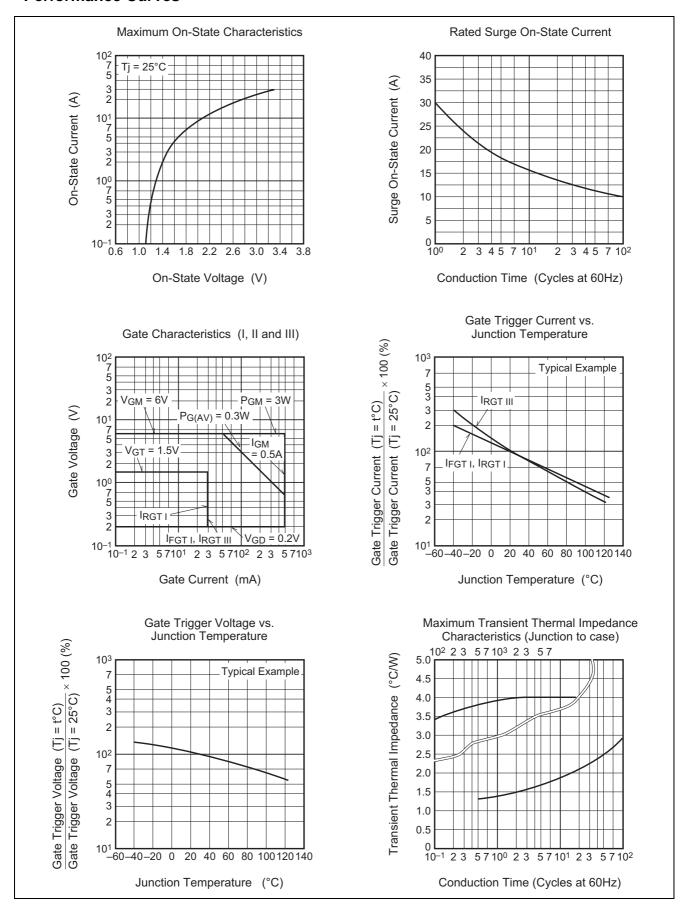
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	_	_	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V_{TM}	_	_	1.6	V	Tc = 25°C, I _{TM} = 4.5 A, Instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}		_	1.5	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V_{RGTIII}	_	_	1.5	V	
Gate trigger current ^{Note2}	I	I _{FGTI}	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	I_{RGTI}	-	_	30	mA	$R_G = 330 \Omega$
	III	I_{RGTIII}	_	_	30	mA	
Gate non-trigger voltage		$V_{\sf GD}$	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	_	4.0	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state commutating voltage ^{Note4}		(dv/dt)c	5	_	_	V/μs	Tj = 125°C

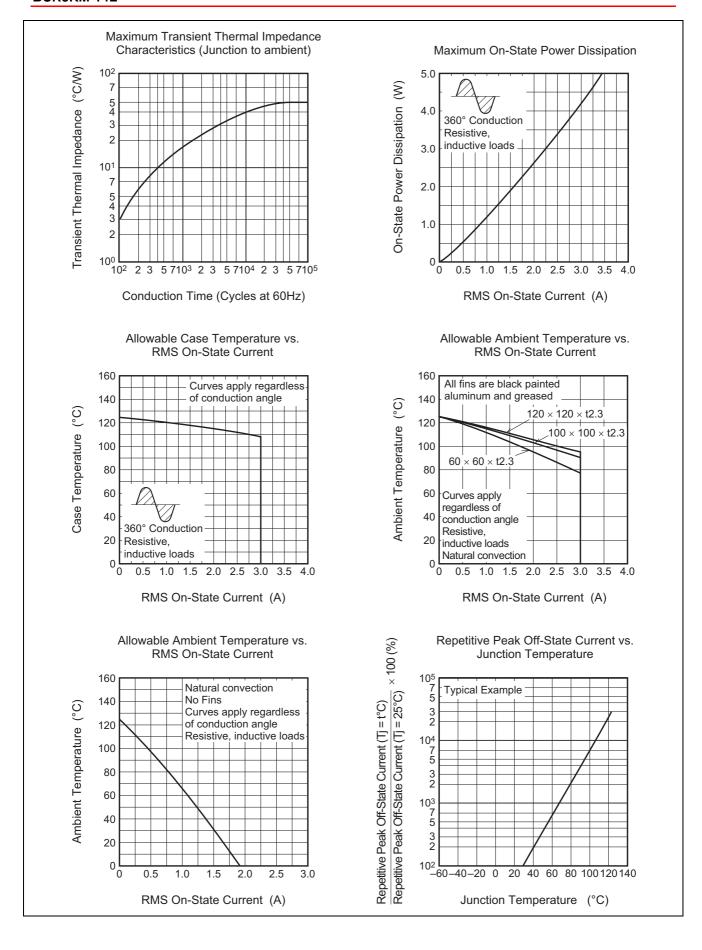
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

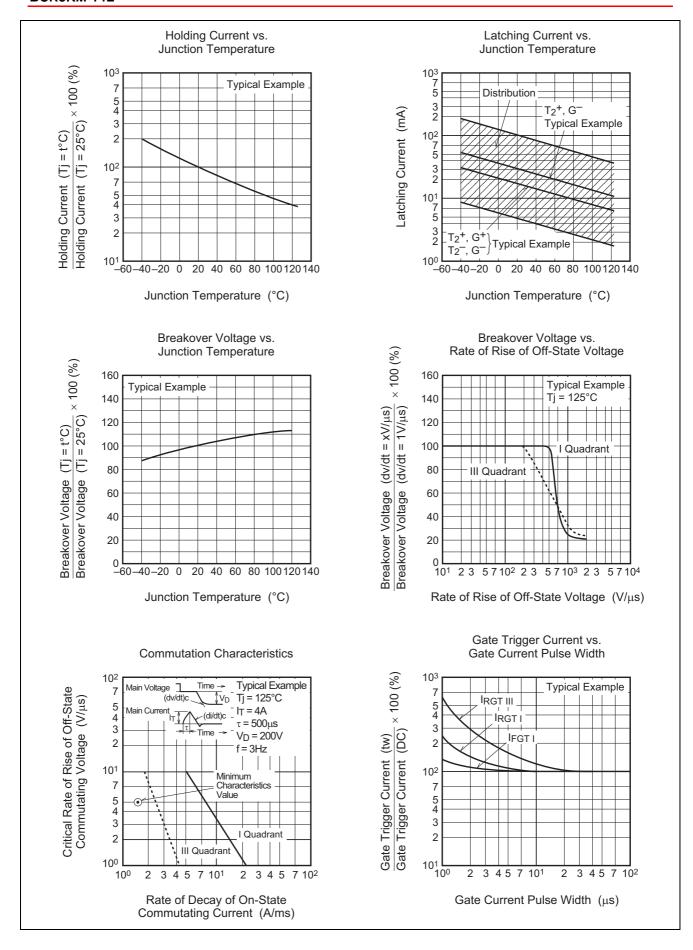
- 3. The contact thermal resistance $R_{th\ (c\text{-}f)}$ in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

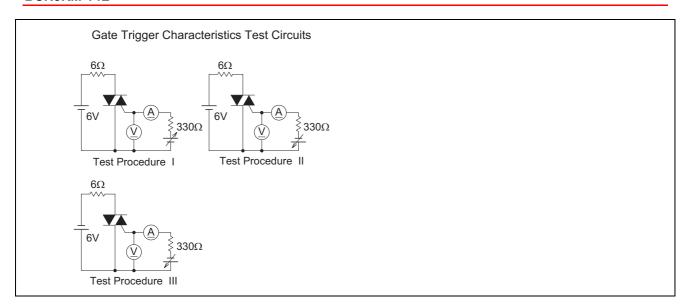
Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature Tj = 125°C	Supply Voltage →Time		
2. Rate of decay of on-state commutating current (di/dt)c = −1.5 A/ms	Main Current (di/dt)c → Time		
3. Peak off-state voltage V _D = 400 V	Main Voltage Time		

Performance Curves

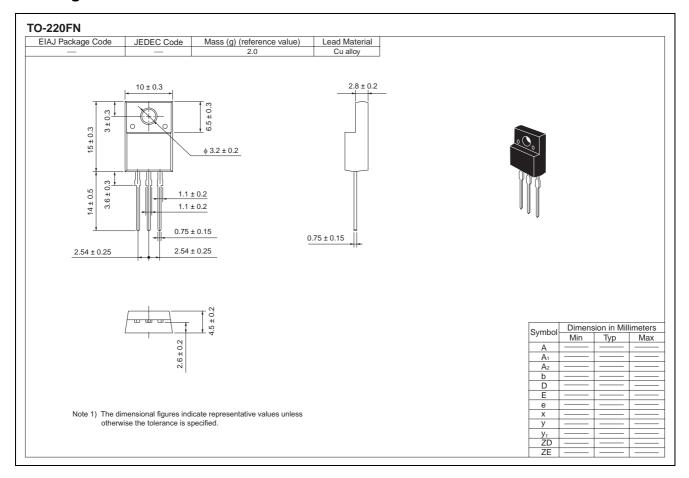








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name +A	BCR3KM-14LA
Lead form	Plastic Magazine (Tube)	50	Type name +A – Lead forming code	BCR3KM-14LA-A8

Note: Please confirm the specification about the shipping in detail.

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